

LP3874-ADJ 0.8A Fast Ultra Low Dropout Linear Regulators

Check for Samples: LP3874-ADJ

FEATURES

- Ultra Low Dropout Voltage
- Low Ground Pin Current
- Load Regulation of 0.04%
- 10nA Quiescent Current in Shutdown Mode
- Specified Output Current of 0.8A DC
- Available in DDPAK/TO-263, TO-220 and SOT-223 Packages
- Minimum Output Capacitor Requirements
- Overtemperature/Overcurrent Protection
- -40°C to +125°C Junction Temperature Range

APPLICATIONS

- Microprocessor Power Supplies
- GTL, GTL+, BTL, and SSTL Bus Terminators
- Power Supplies for DSPs
- SCSI Terminator
- Post Regulators
- High Efficiency Linear Regulators
- Battery Chargers
- Other Battery Powered Applications

DESCRIPTION

The LP3874-ADJ fast ultra low-dropout linear regulators operate from a +2.5V to +7.0V input supply. These ultra low dropout linear regulators respond very quickly to step changes in load, which makes them suitable for low voltage microprocessor applications. The LP3874-ADJ is developed on a CMOS process which allows low quiescent current operation independent of output load current. This CMOS process also allows the LP3874-ADJ to operate under extremely low dropout conditions.

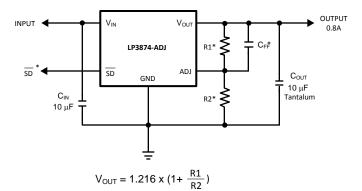
Dropout Voltage: Ultra low dropout voltage; typically 24mV at 80mA load current and 240mV at 0.8A load current.

Ground Pin Current: Typically 6mA at 0.8A load current.

Shutdown Mode: Typically 10nA quiescent current when the shutdown pin is pulled low.

Adjustable Output Voltage: The output voltage may be programmed via two external resistors.

TYPICAL APPLICATION CIRCUIT



*See Application Hints

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Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.





These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

CONNECTION DIAGRAMS

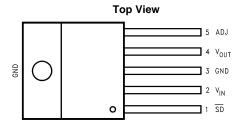


Figure 1. TO-220-5 Package Bent, Staggered Leads See Package Number NDH0005D

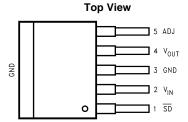


Figure 2. DDPAK/TO-263-5 Package See Package Number KTT0005B

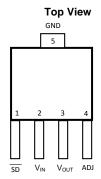


Figure 3. SOT-223-5 Package See Package Number NDC0005A

Table 1. PIN DESCRIPTIONS for TO-220-5 and DDPAK/TO-263-5 Packages

| Pin # | LP3874-ADJ | | | | | | |
|-------|------------------|--------------------|--|--|--|--|--|
| PIN# | Name | Function | | | | | |
| 1 | SD | Shutdown | | | | | |
| 2 | V _{IN} | Input Supply | | | | | |
| 3 | GND | Ground | | | | | |
| 4 | V _{OUT} | Output Voltage | | | | | |
| 5 | ADJ | Set Output Voltage | | | | | |

Table 2. PIN DESCRIPTIONS for SOT-223-5 Package

| Pin # | LP3874-ADJ | | | | | |
|--------|------------------|--------------------|--|--|--|--|
| FIII # | Name | Function | | | | |
| 1 | SD | Shutdown | | | | |
| 2 | V _{IN} | Input Supply | | | | |
| 3 | V _{OUT} | Output Voltage | | | | |
| 4 | ADJ | Set Output Voltage | | | | |
| 5 | GND | Ground | | | | |



BLOCK DIAGRAM

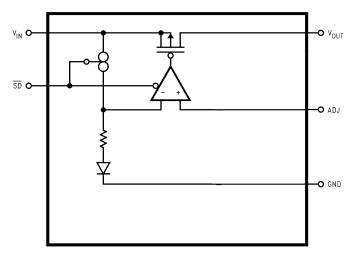


Figure 4. LP3874-ADJ

ABSOLUTE MAXIMUM RATINGS (1)

If Military/Aerospace specified devices are required, contact the Texas Instruments Semiconductor Sales Office/ Distributors for availability and specifications.

| Storage Temperature Range | −65°C to +150°C |
|--------------------------------------|-------------------------|
| Lead Temperature (Soldering, 5 sec.) | 260°C |
| ESD Rating (2) | 2 kV |
| Power Dissipation (3) | Internally Limited |
| Input Supply Voltage (Survival) | -0.3V to +7.5V |
| Shutdown Input Voltage (Survival) | −0.3V to 7.5V |
| Output Voltage (Survival), (4), (5) | -0.3V to +6.0V |
| I _{OUT} (Survival) | Short Circuit Protected |

- (1) Absolute maximum ratings indicate limits beyond which damage to the device may occur. Operating ratings indicate conditions for which the device is intended to be functional, but does not ensure specific performance limits. For ensured specifications and test conditions, see Electrical Characteristics. The ensured specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) The human body model is a 100pF capacitor discharged through a $1.5k\Omega$ resistor into each pin.
- (3) At elevated temperatures, devices must be derated based on package thermal resistance. The devices in TO-220 package must be derated at $\theta_{jA} = 50$ °C/W (with 0.5in², 1oz. copper area), junction-to-ambient (with no heat sink). The devices in the DDPAK/TO-263 surface-mount package must be derated at $\theta_{jA} = 60$ °C/W (with 0.5in², 1oz. copper area), junction-to-ambient. The SOT-223 package must be derated at $\theta_{jA} = 90$ °C/W (with 0.5in², 1oz. copper area), junction-to-ambient.
- (4) If used in a dual-supply system where the regulator load is returned to a negative supply, the output must be diode-clamped to ground.
- (5) The output PMOS structure contains a diode between the V_{IN} and V_{OUT} terminals. This diode is normally reverse biased. This diode will get forward biased if the voltage at the output terminal is forced to be higher than the voltage at the input terminal. This diode can typically withstand 200mA of DC current and 1Amp of peak current.

RECOMMENDED OPERATING CONDITIONS

| Input Supply Voltage (Operating), (1) | 2.5V to 7.0V |
|---------------------------------------|-----------------|
| Shutdown Input Voltage (Operating) | -0.3V to 7.0V |
| Maximum Operating Current (DC) | 0.8A |
| Operating Junction Temp. Range | −40°C to +125°C |

(1) The minimum operating value for V_{IN} is equal to either [V_{OUT(NOM)} + V_{DROPOUT}] or 2.5V, whichever is greater.



ELECTRICAL CHARACTERISTICS LP3874-ADJ

Limits in standard typeface are for $T_J = 25$ °C, and limits in **boldface type** apply over the **full operating temperature range**. Unless otherwise specified: $V_{IN} = V_{O(NOM)} + 1V$, $I_L = 10$ mA, $C_{OUT} = 10\mu F$, $V_{SD} = 2V$.

| Symbol | Parameter | Conditions | Typ ⁽¹⁾ | LP3874 | Units | | | |
|------------------------------------|-----------------------------------|--|---------------------|-----------------------|-----------------------|---------|--|--|
| | | | | Min | Max | | | |
| V_{ADJ} | Adjust Pin Voltage | $V_{OUT} + 1V \le V_{IN} \le 7V$, 10 mA $\le I_L \le 0.8A$ | 1.216 | 1.198 1.180 | 1.234 1.253 | V | | |
| I _{ADJ} | Adjust Pin Input Current | $V_{OUT} + 1V \le V_{IN} \le 7V$, 10 mA $\le I_L \le 0.8A$ | 10 | | 100 | nA | | |
| ΔV _{OL} | Output Voltage Line Regulation | $V_{OUT} + 1V \le V_{IN} \le 7.0V$ | 0.02 0.06 | | | % | | |
| $\Delta V_{O} / \Delta I_{OUT}$ | Output Voltage Load Regulation | 10 mA ≤ I _L ≤ 0.8A | 0.04 0.1 | | | % | | |
| V _{IN} - V _{OUT} | Daniel (4) | I _L = 80 mA | 24 | | 35 40 | >/ | | |
| | Dropout Voltage (4) | I _L = 0.8A | 240 | | 300 350 | mV | | |
| | Ground Pin Current In Normal | I _L = 80 mA | 5 | | 9 10 | 0 | | |
| I _{GND} | Operation Mode | I _L = 0.8A | 6 | | 14 15 | mA | | |
| I _{GND} | Ground Pin Current In Shutdown | V _{SD} ≤ 0.3V | 0.01 | | 10 | μA | | |
| | Mode | -40°C ≤ T _J ≤ 85°C | | | 50 | | | |
| I _{O(PK)} | Peak Output Current | V _O ≥ V _{O(NOM)} - 4% | 1 | | | Α | | |
| Short Circuit I | Protection | | | | | • | | |
| I _{SC} | Short Circuit Current | | 2.3 | | | Α | | |
| Shutdown Inp | out | | | - | | | | |
| | Object de constitution de la late | Output = High | V _{IN} | 2 | | ., | | |
| V_{SDT} | Shutdown Threshold | Output = Low | 0 | | 0.3 | V | | |
| T _{dOFF} | Turn-off delay | $I_L = 0.8A$ | 20 | | | μs | | |
| T _{dON} | Turn-on delay | I _L = 0.8A | 25 | | | μs | | |
| I _{SD} | SD Input Current | $V_{SD} = V_{IN}$ | 1 | | | nA | | |
| AC Parameter | 's | | | | | * | | |
| DCDD | Bissle Brisstian | V _{IN} = V _{OUT} + 1V, C _{OUT} = 10uF V _{OUT} = 3.3V, f = 120Hz | 73 | | | 40 | | |
| PSRR | Ripple Rejection | V _{IN} = V _{OUT} + 0.5V, C _{OUT} = 10uF V _{OUT} = 3.3V, f = 120Hz | 57 | | | dB | | |
| $\rho_{n(I/f)}$ | Output Noise Density | f = 120Hz | 0.8 | | . | μV | | |
| | Output Noise Veltage | BW = 10Hz - 100kHz, V _{OUT} = 2.5V | 150 | | | 11/// | | |
| e _n | Output Noise Voltage | BW = 300Hz - 300kHz, V _{OUT} = 2.5V | 100 | | | μV (rms | | |

⁽¹⁾ Typical numbers are at 25°C and represent the most likely parametric norm.

⁽²⁾ Limits are specified by testing, design, or statistical correlation.

Output voltage line regulation is defined as the change in output voltage from the nominal value due to change in the input line voltage. Output voltage load regulation is defined as the change in output voltage from the nominal value due to change in load current.

⁽⁴⁾ Dropout voltage is defined as the minimum input to output differential voltage at which the output drops 2% below the nominal value. Dropout voltage specification applies only to output voltages of 2.5V and above. For output voltages below 2.5V, the drop-out voltage is nothing but the input to output differential, since the minimum input voltage is 2.5V.



TYPICAL PERFORMANCE CHARACTERISTICS

Unless otherwise specified: $T_J = 25$ °C, $C_{OUT} = 10 \mu F$, $C_{IN} = 10 \mu F$, S/D pin is tied to V_{IN} , $V_{OUT} = 2.5 V$, $V_{IN} = V_{O(NOM)} + 1 V$, $I_L = 10 \text{ mA}$

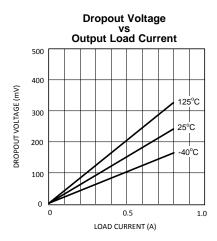


Figure 5.

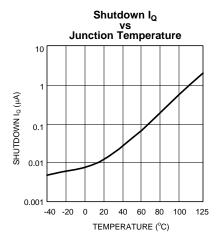
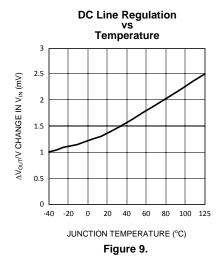


Figure 7.



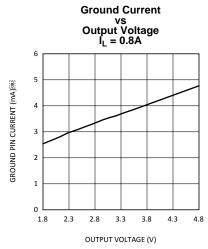
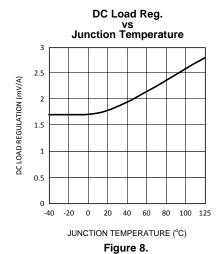


Figure 6.



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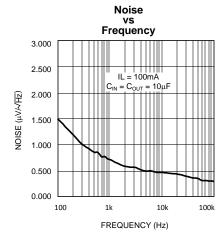


Figure 10.



TYPICAL PERFORMANCE CHARACTERISTICS (continued)

Unless otherwise specified: T_J = 25°C, C_{OUT} = 10 μ F, C_{IN} = 10 μ F, S/D pin is tied to V_{IN} , V_{OUT} = 2.5V, V_{IN} = $V_{O(NOM)}$ + 1V, I_L = 10 mA

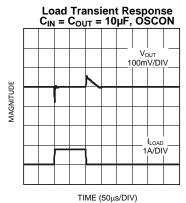
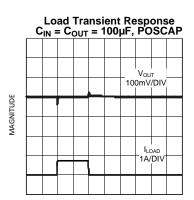


Figure 11.



TIME (50μs/DIV) Figure 13.

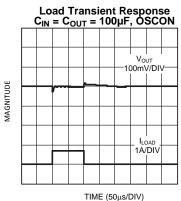


Figure 12.

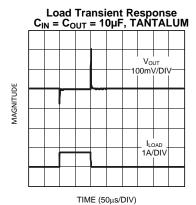


Figure 14.

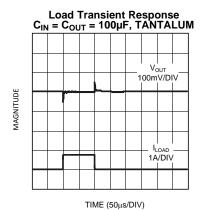


Figure 15.



Application Hints

SETTING THE OUTPUT VOLTAGE

The output voltage is set using the resistors R1 and R2 (see TYPICAL APPLICATION CIRCUIT). The output is also dependent on the reference voltage (typically 1.216V) which is measured at the ADJ pin. The output voltage is given by the equation:

$$V_{OUT} = V_{ADJ} \times (1 + R1 / R2)$$
 (1)

This equation does not include errors due to the bias current flowing in the ADJ pin which is typically about 10 nA. This error term is negligible for most applications. If R1 is > $100k\Omega$, a small error may be introduced by the ADJ bias current.

The tolerance of the external resistors used contributes a significant error to the output voltage accuracy, with 1% resistors typically adding a total error of approximately 1.4% to the output voltage (this error is in addition to the tolerance of the reference voltage at $V_{AD,I}$).

TURN-ON CHARACTERISTICS FOR OUTPUT VOLTAGES PROGRAMMED TO 2.0V OR BELOW

As Vin increases during start-up, the regulator output will track the input until Vin reaches the minimum operating voltage (typically about 2.2V). For output voltages programmed to 2.0V or below, the regulator output may momentarily exceed its programmed output voltage during start up. Outputs programmed to voltages above 2.0V are not affected by this behavior.

EXTERNAL CAPACITORS

Like any low-dropout regulator, external capacitors are required to assure stability. These capacitors must be correctly selected for proper performance.

INPUT CAPACITOR: An input capacitor of at least 10µF is required. Ceramic, Tantalum, or Electrolytic capacitors may be used, and capacitance may be increased without limit.

OUTPUT CAPACITOR: An output capacitor is required for loop stability. It must be located less than 1 cm from the device and connected directly to the output and ground pins using traces which have no other currents flowing through them (see TYPICAL APPLICATION CIRCUIT).

The minimum value of output capacitance that can be used for stable full-load operation is 10µF, but it may be increased without limit. The output capacitor must have an ESR value as shown in the stable region of the curve (below). Tantalum capacitors are recommended for the output capacitor.

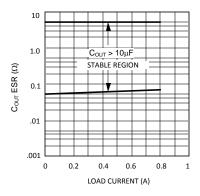


Figure 16. ESR Curve

CFF (Feed Forward Capacitor)

The capacitor C_{FF} is required to add phase lead and help improve loop compensation. The correct amount of capacitance depends on the value selected for R1 (see TYPICAL APPLICATION CIRCUIT). The capacitor should be selected such that the zero frequency as given by the equation shown below is approximately 45 kHz:

$$Fz = 45,000 = 1 / (2 \times \pi \times R1 \times C_{FF})$$
 (2)

A good quality ceramic with X5R or X7R dielectric should be used for this capacitor.

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SELECTING A CAPACITOR

It is important to note that capacitance tolerance and variation with temperature must be taken into consideration when selecting a capacitor so that the minimum required amount of capacitance is provided over the full operating temperature range. In general, a good Tantalum capacitor will show very little capacitance variation with temperature, but a ceramic may not be as good (depending on dielectric type). Aluminum electrolytics also typically have large temperature variation of capacitance value.

Equally important to consider is a capacitor's ESR change with temperature: this is not an issue with ceramics, as their ESR is extremely low. However, it is very important in Tantalum and aluminum electrolytic capacitors. Both show increasing ESR at colder temperatures, but the increase in aluminum electrolytic capacitors is so severe they may not be feasible for some applications (see CAPACITOR CHARACTERISTICS).

CAPACITOR CHARACTERISTICS

CERAMIC: For values of capacitance in the 10 to 100 μ F range, ceramics are usually larger and more costly than tantalums but give superior AC performance for bypassing high frequency noise because of very low ESR (typically less than 10 m Ω). However, some dielectric types do not have good capacitance characteristics as a function of voltage and temperature.

Z5U and Y5V dielectric ceramics have capacitance that drops severely with applied voltage. A typical Z5U or Y5V capacitor can lose 60% of its rated capacitance with half of the rated voltage applied to it. The Z5U and Y5V also exhibit a severe temperature effect, losing more than 50% of nominal capacitance at high and low limits of the temperature range.

X7R and X5R dielectric ceramic capacitors are strongly recommended if ceramics are used, as they typically maintain a capacitance range within ±20% of nominal over full operating ratings of temperature and voltage. Of course, they are typically larger and more costly than Z5U/Y5U types for a given voltage and capacitance.

TANTALUM: Solid Tantalum capacitors are recommended for use on the output because their typical ESR is very close to the ideal value required for loop compensation. They also work well as input capacitors if selected to meet the ESR requirements previously listed.

Tantalums also have good temperature stability: a good quality Tantalum will typically show a capacitance value that varies less than 10-15% across the full temperature range of 125°C to −40°C. ESR will vary only about 2X going from the high to low temperature limits.

The increasing ESR at lower temperatures can cause oscillations when marginal quality capacitors are used (if the ESR of the capacitor is near the upper limit of the stability range at room temperature).

ALUMINUM: This capacitor type offers the most capacitance for the money. The disadvantages are that they are larger in physical size, not widely available in surface mount, and have poor AC performance (especially at higher frequencies) due to higher ESR and ESL.

Compared by size, the ESR of an aluminum electrolytic is higher than either Tantalum or ceramic, and it also varies greatly with temperature. A typical aluminum electrolytic can exhibit an ESR increase of as much as 50X when going from $25^{\circ}C$ down to $-40^{\circ}C$.

It should also be noted that many aluminum electrolytics only specify impedance at a frequency of 120 Hz, which indicates they have poor high frequency performance. Only aluminum electrolytics that have an impedance specified at a higher frequency (between 20 kHz and 100 kHz) should be used for the LP387X. Derating must be applied to the manufacturer's ESR specification, since it is typically only valid at room temperature.

Any applications using aluminum electrolytics should be thoroughly tested at the lowest ambient operating temperature where ESR is maximum.

PCB LAYOUT

Good PC layout practices must be used or instability can be induced because of ground loops and voltage drops. The input and output capacitors must be directly connected to the input, output, and ground pins of the LP387X using traces which do not have other currents flowing in them (Kelvin connect).

The best way to do this is to lay out C_{IN} and C_{OUT} near the device with short traces to the V_{IN} , V_{OUT} , and ground pins. The regulator ground pin should be connected to the external circuit ground so that the regulator and its capacitors have a "single point ground".

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It should be noted that stability problems have been seen in applications where "vias" to an internal ground plane were used at the ground points of the IC and the input and output capacitors. This was caused by varying ground potentials at these nodes resulting from current flowing through the ground plane. Using a single point ground technique for the regulator and it's capacitors fixed the problem.

Since high current flows through the traces going into V_{IN} and coming from V_{OUT} , Kelvin connect the capacitor leads to these pins so there is no voltage drop in series with the input and output capacitors.

RFI/EMI SUSCEPTIBILITY

RFI (radio frequency interference) and EMI (electromagnetic interference) can degrade any integrated circuit's performance because of the small dimensions of the geometries inside the device. In applications where circuit sources are present which generate signals with significant high frequency energy content (> 1 MHz), care must be taken to ensure that this does not affect the IC regulator.

If RFI/EMI noise is present on the input side of the regulator (such as applications where the input source comes from the output of a switching regulator), good ceramic bypass capacitors must be used at the input pin of the IC.

If a load is connected to the IC output which switches at high speed (such as a clock), the high-frequency current pulses required by the load must be supplied by the capacitors on the IC output. Since the bandwidth of the regulator loop is less than 100 kHz, the control circuitry cannot respond to load changes above that frequency. The means the effective output impedance of the IC at frequencies above 100 kHz is determined only by the output capacitor(s).

In applications where the load is switching at high speed, the output of the IC may need RF isolation from the load. It is recommended that some inductance be placed between the output capacitor and the load, and good RF bypass capacitors be placed directly across the load.

PCB layout is also critical in high noise environments, since RFI/EMI is easily radiated directly into PC traces. Noisy circuitry should be isolated from "clean" circuits where possible, and grounded through a separate path. At MHz frequencies, ground planes begin to look inductive and RFI/EMI can cause ground bounce across the ground plane.

In multi-layer PCB applications, care should be taken in layout so that noisy power and ground planes do not radiate directly into adjacent layers which carry analog power and ground.

OUTPUT NOISE

Noise is specified in two ways-

Spot Noise or **Output noise density** is the RMS sum of all noise sources, measured at the regulator output, at a specific frequency (measured with a 1Hz bandwidth). This type of noise is usually plotted on a curve as a function of frequency.

Total output Noise or **Broad-band noise** is the RMS sum of spot noise over a specified bandwidth, usually several decades of frequencies.

Attention should be paid to the units of measurement. Spot noise is measured in units $\mu V/\sqrt{Hz}$ or nV/\sqrt{Hz} and total output noise is measured in $\mu V(rms)$.

The primary source of noise in low-dropout regulators is the internal reference. In CMOS regulators, noise has a low frequency component and a high frequency component, which depend strongly on the silicon area and quiescent current. Noise can be reduced in two ways: by increasing the transistor area or by increasing the current drawn by the internal reference. Increasing the area will decrease the chance of fitting the die into a smaller package. Increasing the current drawn by the internal reference increases the total supply current (ground pin current). Using an optimized trade-off of ground pin current and die size, LP3871/LP3874 achieves low noise performance and low quiescent current operation.

The total output noise specification for LP3871/LP3874 is presented in the Electrical Characteristics table. The Output noise density at different frequencies is represented by a curve under typical performance characteristics.

Product Folder Links: LP3874-ADJ



SHORT-CIRCUIT PROTECTION

The LP3874-ADJ is short circuit protected and in the event of a peak over-current condition, the short-circuit control loop will rapidly drive the output PMOS pass element off. Once the power pass element shuts down, the control loop will rapidly cycle the output on and off until the average power dissipation causes the thermal shutdown circuit to respond to servo the on/off cycling to a lower frequency. Please refer to the section on thermal information for power dissipation calculations.

SHUTDOWN OPERATION

A CMOS Logic level signal at the shutdown (SD) pin will turn-off the regulator. Pin SD must be actively terminated through a $10k\Omega$ pull-up resistor for a proper operation. If this pin is driven from a source that actively pulls high and low (such as a CMOS rail to rail comparator), the pull-up resistor is not required. This pin must be tied to Vin if not used.

DROPOUT VOLTAGE

The dropout voltage of a regulator is defined as the minimum input-to-output differential required to stay within 2% of the nominal output voltage. For CMOS LDOs, the dropout voltage is the product of the load current and the Rds(on) of the internal MOSFET.

REVERSE CURRENT PATH

The internal MOSFET in LP3874-ADJ has an inherent parasitic diode. During normal operation, the input voltage is higher than the output voltage and the parasitic diode is reverse biased. However, if the output is pulled above the input in an application, then current flows from the output to the input as the parasitic diode gets forward biased. The output can be pulled above the input as long as the current in the parasitic diode is limited to 200mA continuous and 1A peak.

POWER DISSIPATION/HEATSINKING

The LP3874-ADJ can deliver a continuous current of 0.8A over the full operating temperature range. A heatsink may be required depending on the maximum power dissipation and maximum ambient temperature of the application. Under all possible conditions, the junction temperature must be within the range specified under operating conditions. The total power dissipation of the device is given by:

(3)

$$P_D = (V_{IN} - V_{OUT})I_{OUT} + (V_{IN})I_{GND}$$

where I_{GND} is the operating ground current of the device (specified under Electrical Characteristics).

The maximum allowable temperature rise (T_{Rmax}) depends on the maximum ambient temperature (T_{Amax}) of the application, and the maximum allowable junction temperature (T_{lmax}):

$$T_{Rmax} = T_{Jmax} - T_{Amax}$$
 (4)

The maximum allowable value for junction to ambient Thermal Resistance, θ_{JA} , can be calculated using the formula:

$$\theta_{\mathsf{IA}} = \mathsf{T}_{\mathsf{Rmax}} / \mathsf{P}_{\mathsf{D}} \tag{5}$$

The LP3874-ADJ is available in TO-220 and DDPAK/TO-263 packages. The thermal resistance depends on amount of copper area or heat sink, and on air flow. If the maximum allowable value of θ_{IA} calculated above is \geq 60 °C/W for TO-220 package and ≥ 60 °C/W for DDPAK/TO-263 package no heatsink is needed since the package can dissipate enough heat to satisfy these requirements. If the value for allowable θ_{IA} falls below these limits, a heat sink is required.

HEATSINKING TO-220 PACKAGE

The thermal resistance of a TO220 package can be reduced by attaching it to a heat sink or a copper plane on a PC board. If a copper plane is to be used, the values of θ_{1A} will be same as shown in next section for DDPAK/TO-263 package.

Product Folder Links: LP3874-ADJ

The heatsink to be used in the application should have a heatsink to ambient thermal resistance,

$$\theta_{\text{HA}} \leq \theta_{\text{JA}} - \theta_{\text{CH}} - \theta_{\text{JC}}. \tag{6}$$



In this equation, θ_{CH} is the thermal resistance from the case to the surface of the heat sink and θ_{JC} is the thermal resistance from the junction to the surface of the case. θ_{JC} is about 3°C/W for a TO-220 package. The value for θ_{CH} depends on method of attachment, insulator, etc. θ_{CH} varies between 1.5°C/W to 2.5°C/W. If the exact value is unknown, 2°C/W can be assumed.

HEATSINKING DDPAK/TO-263 PACKAGE

The DDPAK/TO-263 package uses the copper plane on the PCB as a heatsink. The tab of these packages are soldered to the copper plane for heat sinking. Figure 17 shows a curve for the θ_{JA} of DDPAK/TO-263 package for different copper area sizes, using a typical PCB with 1 ounce copper and no solder mask over the copper area for heat sinking.

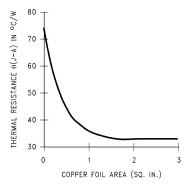


Figure 17. θ_{JA} vs Copper (1 Ounce) Area for DDPAK/TO-263 package

As shown in the figure, increasing the copper area beyond 1 square inch produces very little improvement. The minimum value for θ_{1A} for the DDPAK/TO-263 package mounted to a PCB is 32°C/W.

Figure 18 shows the maximum allowable power dissipation for DDPAK/TO-263 packages for different ambient temperatures, assuming θ_{1A} is 35°C/W and the maximum junction temperature is 125°C.

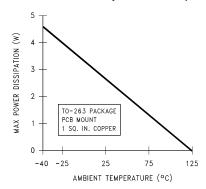


Figure 18. Maximum power dissipation vs ambient temperature for DDPAK/TO-263 package

HEATSINKING SOT223-5 PACKAGE

Figure 19 shows a curve for the θ_{JA} of SOT-223 package for different copper area sizes, using a typical PCB with 1 ounce copper and no solder mask over the copper area for heat sinking.

Product Folder Links: LP3874-ADJ

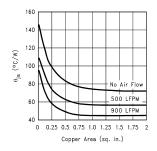


Figure 19. θ_{JA} vs Copper(1 Ounce) Area for SOT-223 package

The following figures show different layout scenarios for SOT-223 package.

Area =
$$0.0078$$
 sq. in.

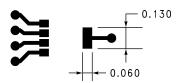


Figure 20. SCENARIO A, $\theta_{JA} = 148$ °C/W

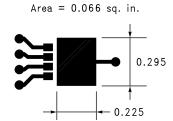


Figure 21. SCENARIO B, $\theta_{JA} = 125$ °C/W





REVISION HISTORY

| Changes from Revision D (April 2013) to Revision E | | | | | | |
|--|--|--|----|--|--|--|
| • | Changed layout of National Data Sheet to TI format | | 12 | | | |

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PACKAGING INFORMATION

| Orderable part number | Status | Material type | Package Pins | Package qty Carrier | RoHS | Lead finish/ MSL rating/ Ball material Peak reflow | | Op temp (°C) | Part marking |
|-----------------------|--------|---------------|----------------------------|-----------------------|-------------|--|---------------------|--------------|-----------------|
| | (-) | (=/ | | | (-) | (4) | (5) | | (5) |
| LP3874EMP-ADJ/NOPB | Active | Production | SOT-223 (NDC) 5 | 1000 SMALL T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | LHKB |
| LP3874EMP-ADJ/NOPB.A | Active | Production | SOT-223 (NDC) 5 | 1000 SMALL T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | LHKB |
| LP3874EMPX-ADJ/NO.A | Active | Production | SOT-223 (NDC) 5 | 2000 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | LHKB |
| LP3874EMPX-ADJ/NOPB | Active | Production | SOT-223 (NDC) 5 | 2000 LARGE T&R | Yes | SN | Level-1-260C-UNLIM | -40 to 125 | LHKB |
| LP3874ES-ADJ/NOPB | Active | Production | DDPAK/ TO-263 (KTT) 5 | 45 TUBE | ROHS Exempt | SN | Level-3-245C-168 HR | -40 to 125 | LP3874ES ADJ |
| LP3874ES-ADJ/NOPB.A | Active | Production | DDPAK/ TO-263 (KTT) 5 | 45 TUBE | ROHS Exempt | SN | Level-3-245C-168 HR | -40 to 125 | LP3874ES ADJ |
| LP3874ESX-ADJ/NOPB | Active | Production | DDPAK/ TO-263 (KTT) 5 | 500 LARGE T&R | ROHS Exempt | SN | Level-3-245C-168 HR | -40 to 125 | LP3874ES ADJ |
| LP3874ESX-ADJ/NOPB.A | Active | Production | DDPAK/ TO-263 (KTT) 5 | 500 LARGE T&R | ROHS Exempt | SN | Level-3-245C-168 HR | -40 to 125 | LP3874ES ADJ |

⁽¹⁾ Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

⁽²⁾ Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

⁽⁴⁾ Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



PACKAGE OPTION ADDENDUM

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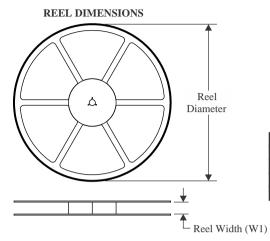
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PACKAGE MATERIALS INFORMATION

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TAPE AND REEL INFORMATION



TAPE DIMENSIONS + K0 - P1 - B0 W Cavity - A0 -

| A0 | Dimension designed to accommodate the component width |
|----|---|
| В0 | Dimension designed to accommodate the component length |
| K0 | Dimension designed to accommodate the component thickness |
| W | Overall width of the carrier tape |
| P1 | Pitch between successive cavity centers |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE

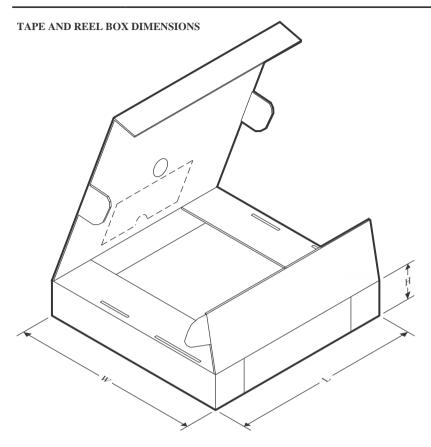


*All dimensions are nominal

| Device | Package Type | Package Drawing | | SPQ | Reel Diameter (mm) | Reel Width W1 (mm) | A0 (mm) | B0 (mm) | K0 (mm) | P1 (mm) | W (mm) | Pin1 Quadrant |
|---------------------|------------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| LP3874EMP-ADJ/NOPB | SOT-223 | NDC | 5 | 1000 | 330.0 | 16.4 | 7.0 | 7.5 | 2.2 | 12.0 | 16.0 | Q3 |
| LP3874EMPX-ADJ/NOPB | SOT-223 | NDC | 5 | 2000 | 330.0 | 16.4 | 7.0 | 7.5 | 2.2 | 12.0 | 16.0 | Q3 |
| LP3874ESX-ADJ/NOPB | DDPAK/ TO-263 | KTT | 5 | 500 | 330.0 | 24.4 | 10.75 | 14.85 | 5.0 | 16.0 | 24.0 | Q2 |



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*All dimensions are nominal

| Device | Package Type | Package Drawing | Pins | SPQ | Length (mm) | Width (mm) | Height (mm) |
|---------------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LP3874EMP-ADJ/NOPB | SOT-223 | NDC | 5 | 1000 | 367.0 | 367.0 | 35.0 |
| LP3874EMPX-ADJ/NOPB | SOT-223 | NDC | 5 | 2000 | 367.0 | 367.0 | 35.0 |
| LP3874ESX-ADJ/NOPB | DDPAK/TO-263 | KTT | 5 | 500 | 356.0 | 356.0 | 45.0 |

PACKAGE MATERIALS INFORMATION

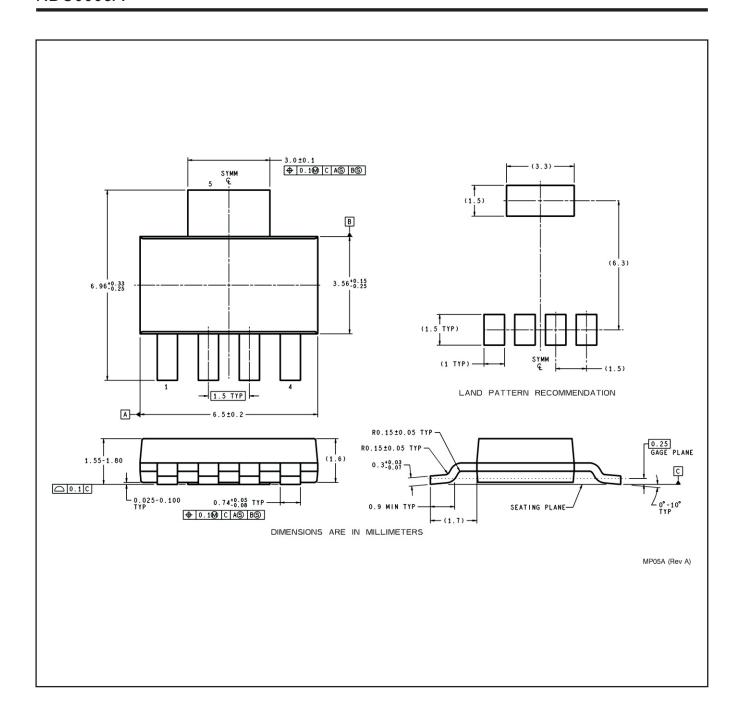
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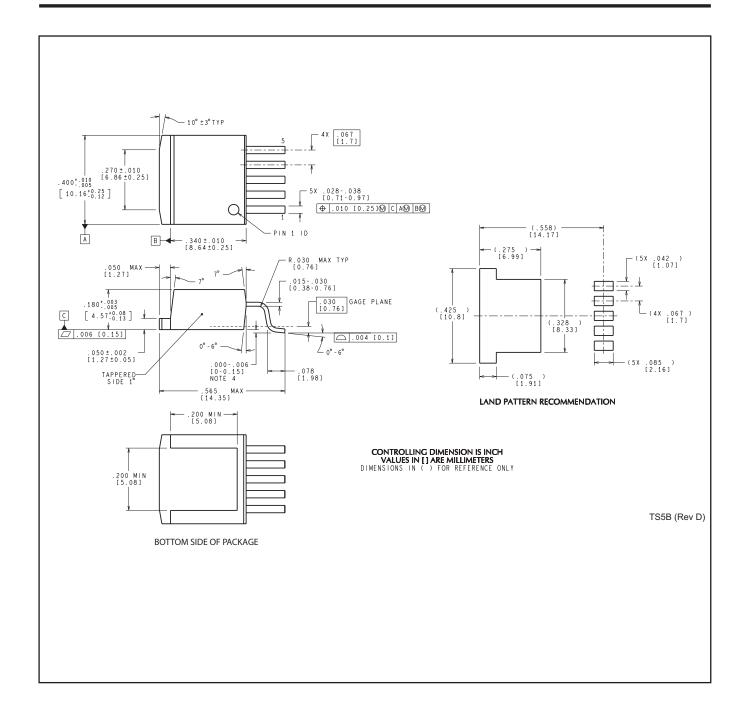
TUBE



*All dimensions are nominal

| Device | Package Name | Package Type | Pins | SPQ | L (mm) | W (mm) | T (µm) | B (mm) |
|---------------------|--------------|--------------|------|-----|--------|--------|--------|--------|
| LP3874ES-ADJ/NOPB | KTT | TO-263 | 5 | 45 | 502 | 25 | 8204.2 | 9.19 |
| LP3874ES-ADJ/NOPB.A | ктт | TO-263 | 5 | 45 | 502 | 25 | 8204.2 | 9.19 |





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